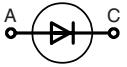
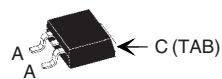
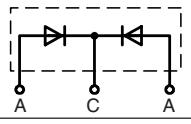


Gallium Arsenide Schottky Rectifier

I_{FAV} = 23 A
 V_{RRM} = 180 V
 $C_{Junction}$ = 33 pF

Type	Marking on product	Circuit	Package
A = Anode, C = Cathode , TAB = Cathode			
DGS 20-018A	DGS 20-018A	Single	TO-220 AC 
DGS 20-018AS	DGS 20-018AS	Single	TO-263 AB 
DGSK 40-018A	DGSK 40-018A	Common cathode 	TO-220 AB 

Symbol	Conditions	Maximum Ratings	
$V_{RRM/RSM}$		180	V
I_{FAV}	$T_c = 25^\circ\text{C}$; DC	23	A
I_{FAV}	$T_c = 90^\circ\text{C}$; DC	17	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t_p = 10 \text{ ms}$ (50 Hz), sine	30	A
T_{VJ}		-55...+175	°C
T_{stg}		-55...+150	°C
P_{tot}	$T_c = 25^\circ\text{C}$	48	W
M_d	mounting torque (Versions A only)	0.4...0.6	Nm

Symbol	Conditions	Characteristic Values	
		typ.	max.
I_R ①	$V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$; $T_{VJ} = 125^\circ\text{C}$	2.0	mA
V_F	$I_F = 7.5 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$ $I_F = 7.5 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	0.8	V
I_F	$I_F = 7.5 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$ $I_F = 7.5 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	0.8	V
C_J	$V_R = 100 \text{ V}$; $T_{VJ} = 125^\circ\text{C}$	33	pF
R_{thJC}		3.1	K/W
R_{thCH}	TO-220	0.5	K/W
Weight		2	g

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %
Data according to IEC 60747 and per diode unless otherwise specified

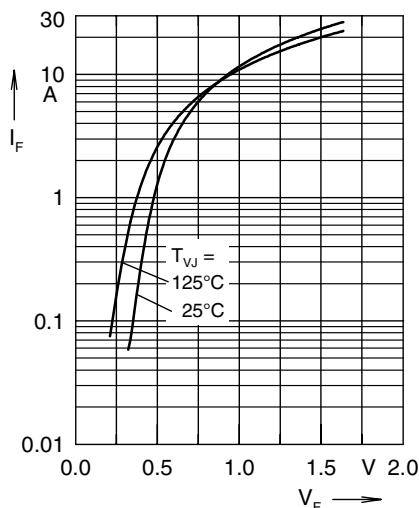


Fig. 1 typ. forward characteristics

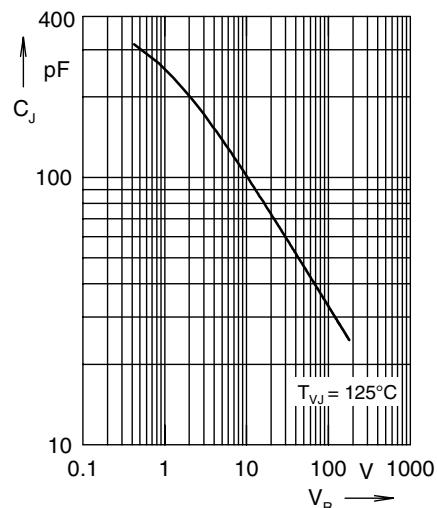


Fig. 2 typ. junction capacity
versus blocking voltage

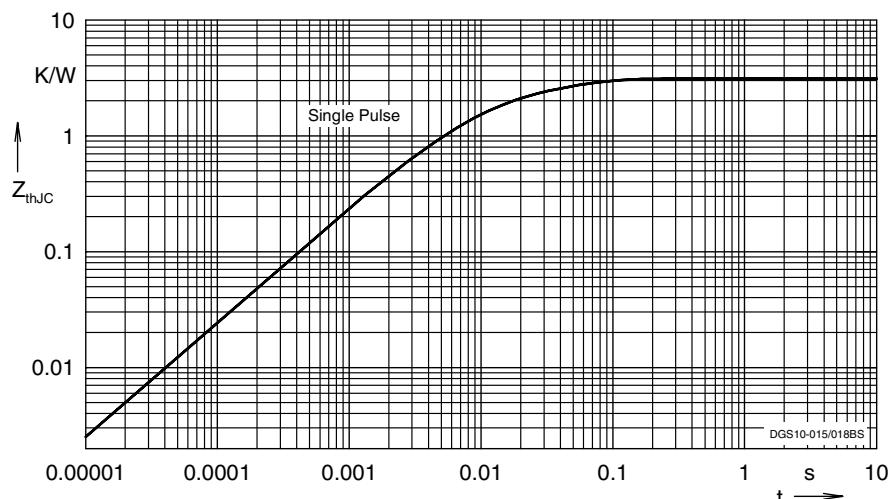


Fig. 3 typ. thermal impedance junction to case

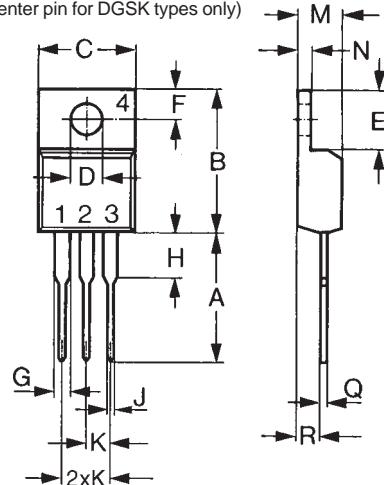
Note:

explanatory comparison of the basic operational behaviour of rectifier diodes and Gallium Arsenide Schottky diodes:

	Rectifier Diode	GaAs Schottky Diode
conduction forward characteristics	by majority + minority carriers V_F (I_F)	by majority carriers only V_F (I_F), see Fig. 1
turn off characteristics	extraction of excess carriers causes temperature dependant reverse recovery (t_{rr} , I_{RM} , Q_r)	reverse current charges junction capacity C_J , see Fig. 2; not temperature dependant
turn on characteristics	delayed saturation leads to V_{FR}	no turn on overvoltage peak

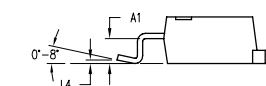
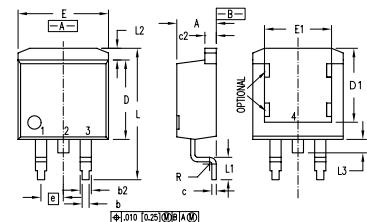
Outline TO-220

(center pin for DGSK types only)



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.38	0.56	0.015	0.022
R	2.29	2.79	0.090	0.110

Outline TO-263 AB



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	4.06	4.83	.160	.190
A1	2.03	2.79	.080	.110
b	0.51	0.99	.020	.039
b2	1.14	1.40	.045	.055
c	0.46	0.74	.018	.029
c2	1.14	1.40	.045	.055
D	8.64	9.65	.340	.380
D1	8.00	8.89	.315	.350
E	9.65	10.29	.380	.405
E1	6.22	8.13	.245	.320
e	2.54	BSC	.100	BSC
L	14.61	15.88	.575	.625
L1	2.29	2.79	.090	.110
L2	1.02	1.40	.040	.055
L3	1.27	1.78	.050	.070
L4	0	0.20	0	.008
R	0.46	0.74	.018	.029